

SMALL SIGNAL PNP TRANSISTOR

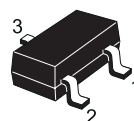
PRELIMINARY DATA

Type	Marking
BC857B	3F

- SILICON EPITAXIAL PLANAR PNP TRANSISTOR
- MINIATURE SOT-23 PLASTIC PACKAGE FOR SURFACE MOUNTING CIRCUITS
- TAPE AND REEL PACKING
- THE NPN COMPLEMENTARY TYPE IS BC847B

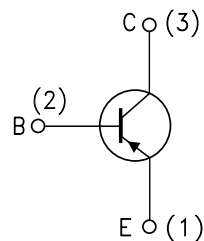
APPLICATIONS

- WELL SUITABLE FOR PORTABLE EQUIPMENT
- SMALL LOAD SWITCH TRANSISTOR WITH HIGH GAIN AND LOW SATURATION VOLTAGE



SOT-23

INTERNAL SCHEMATIC DIAGRAM



DS10120

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage ($I_E = 0$)	-50	V
V_{CEO}	Collector-Emitter Voltage ($I_B = 0$)	-45	V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	-5	V
I_C	Collector Current	-100	mA
I_{CM}	Collector Peak Current	-200	mA
P_{tot}	Total Dissipation at $T_C = 25\text{ }^{\circ}\text{C}$	250	mW
T_{stg}	Storage Temperature	-65 to 150	$^{\circ}\text{C}$
T_j	Max. Operating Junction Temperature	150	$^{\circ}\text{C}$

BC857B

THERMAL DATA

$R_{thj-amb}$ •	Thermal Resistance Junction-Ambient	Max	500	$^{\circ}\text{C}/\text{W}$
-----------------	-------------------------------------	-----	-----	-----------------------------

• Device mounted on a PCB area of 1 cm^2 .

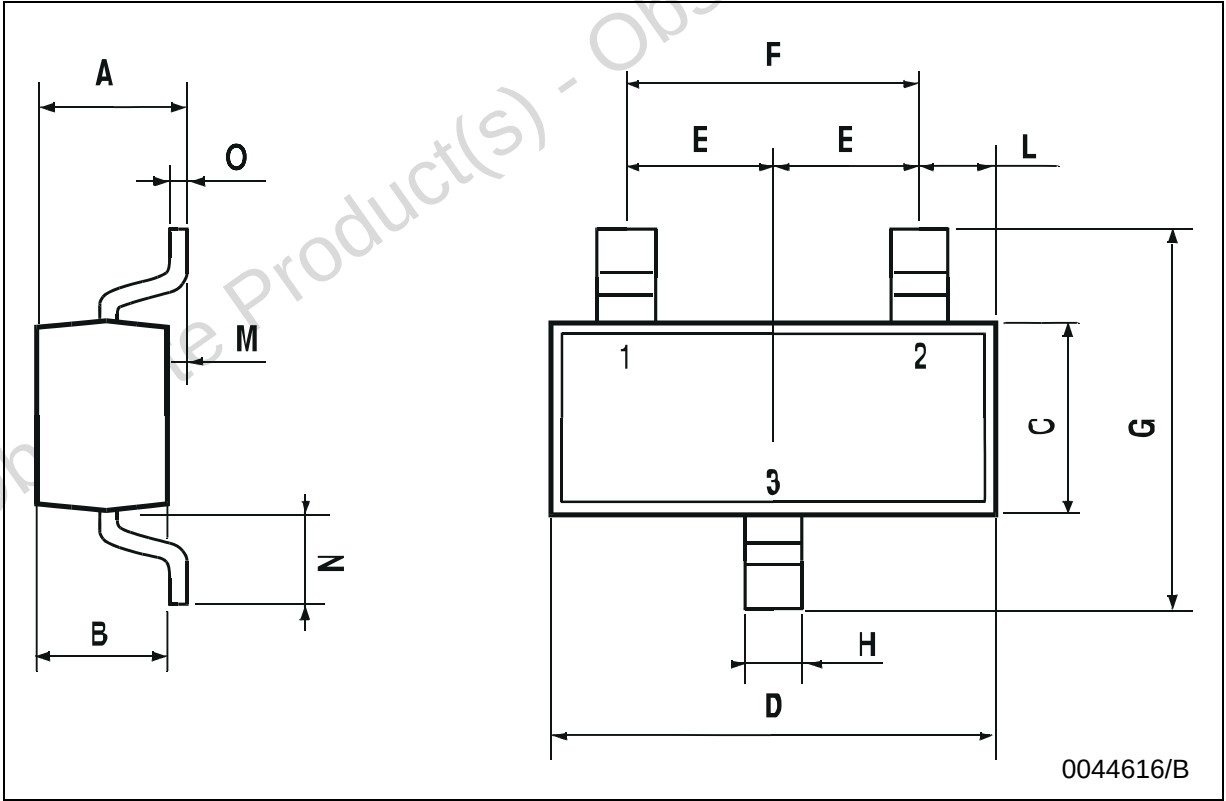
ELECTRICAL CHARACTERISTICS ($T_{\text{case}} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cut-off Current ($I_E = 0$)	$V_{CB} = -30\text{ V}$ $V_{CB} = -30\text{ V}$ $T_C = 150\text{ }^{\circ}\text{C}$		-1	-15 -5	nA μA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = -5\text{ V}$			-100	nA
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage ($I_E = 0$)	$I_C = -10\text{ }\mu\text{A}$	-50			V
$V_{(BR)CEO}^*$	Collector-Emitter Breakdown Voltage ($I_B = 0$)	$I_C = -2\text{ mA}$	-45			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage ($I_C = 0$)	$I_E = -10\text{ }\mu\text{A}$	-5			V
$V_{CE(sat)}^*$	Collector-Emitter Saturation Voltage	$I_C = -10\text{ mA}$ $I_B = -0.5\text{ mA}$ $I_C = -100\text{ mA}$ $I_B = -5\text{ mA}$		-0.07 -0.25	-0.3 -0.65	V V
$V_{BE(sat)}^*$	Base-Emitter Saturation Voltage	$I_C = -10\text{ mA}$ $I_B = -0.5\text{ mA}$ $I_C = -100\text{ mA}$ $I_B = -5\text{ mA}$		-0.7 -0.85		V V
$V_{BE(on)}^*$	Base-Emitter On Voltage	$I_C = -2\text{ mA}$ $V_{CE} = -5\text{ V}$ $I_C = -10\text{ mA}$ $V_{CE} = -5\text{ V}$	-0.6	-0.65	-0.75 -0.82	V V
h_{FE}	DC Current Gain	$I_C = -2\text{ mA}$ $V_{CE} = -5\text{ V}$	220		475	
f_T	Transition Frequency	$I_C = -10\text{ mA}$ $V_{CE} = -5\text{ V}$ $f = 100\text{ MHz}$	100			MHz
C_{CBO}	Collector-Base Capacitance	$I_E = 0$ $V_{CB} = -10\text{ V}$ $f = 1\text{ MHz}$		4.5		pF
NF	Noise Figure	$V_{CE} = -5\text{ V}$ $I_C = -0.2\text{ mA}$ $f = 1\text{ KHz}$ $\Delta f = 200\text{ Hz}$ $R_G = 2\text{ K}\Omega$		2	10	dB

* Pulsed: Pulse duration = $300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

SOT-23 MECHANICAL DATA

DIM.	mm			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	0.85		1.1	33.4		43.3
B	0.65		0.95	25.6		37.4
C	1.20		1.4	47.2		55.1
D	2.80		3	110.2		118
E	0.95		1.05	37.4		41.3
F	1.9		2.05	74.8		80.7
G	2.1		2.5	82.6		98.4
H	0.38		0.48	14.9		18.8
L	0.3		0.6	11.8		23.6
M	0		0.1	0		3.9
N	0.3		0.65	11.8		25.6
O	0.09		0.17	3.5		6.7



Obsolete Product(s) - Obsolete Product(s)

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a trademark of STMicroelectronics

© 2002 STMicroelectronics – Printed in Italy – All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

<http://www.st.com>